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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0032				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0043				
I _D (A)	60				
Configuration	Single				
Package	PowerPAK SO-8L				

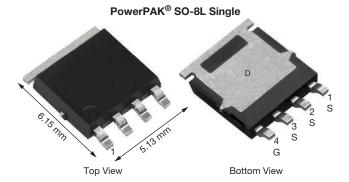
FEATURES

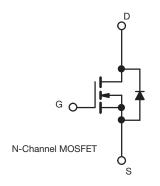
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current ^a	T _C = 25 °C	L	60	A	
	T _C = 125 °C	I _D	60		
Continuous Source Current (Diode conducti	on) ^a	Is	60		
Pulsed Drain Current ^b		I _{DM}	150		
Single Pulse Avalanche Current	ingle Pulse Avalanche Current		25		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	31.2	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	68	W	
	T _C = 125 °C	P_{D}	22		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	
Soldering Recommendations (Peak temperature) d, e			260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB mount c	R_{thJA}	68	°C/W
Junction-to-Case (Drain)		R_{thJC}	2.2	C/VV

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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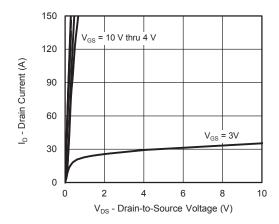
PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		40	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 \text{ V}$	=	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = 40 V	-	-	1	μΑ
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	1	-	50	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	250	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α
		V _{GS} = 10 V	I _D = 10 A	=	0.0026	0.0032	- Ω
Dunin Course On State Desistance 2	В	V _{GS} = 4.5 V	I _D = 8 A	-	0.0034	0.0043	
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A, T _J = 125 °C	=	-	0.0048	
		V _{GS} = 10 V	I _D = 10 A, T _J = 175 °C	=	-	0.0057	
Forward Transconductance b	9fs	V _{DS}	= 15 V, I _D = 10 A	-	80	-	S
Dynamic ^b	•						
Input Capacitance	C _{iss}			=	3700	5000	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	2310	3050	pF
Reverse Transfer Capacitance	C _{rss}			=	160	220	
Total Gate Charge ^c	Qg			=	51	80	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_D = 5 \text{ A}$	-	9	-	nC
Gate-Drain Charge ^c	Q _{gd}		1		7	-	
Gate Resistance	R _g		f = 1 MHz	0.2	0.44	0.7	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	11	20	
Rise Time ^c	t _r	$V_{DD} = 20 \text{ V}, R_{L} = 4 \Omega$		=	19	30	no
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 5 A, Y$	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	30	50	ns
Fall Time ^c	t _f			-	21	35	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	150	Α
Forward Voltage	V_{SD}	I _F = 15 A, V _{GS} = 0		_	0.8	1.2	V

Notes

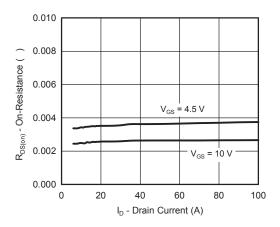
- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

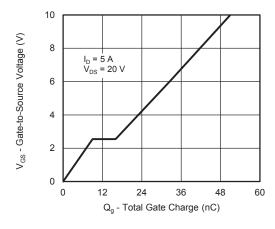




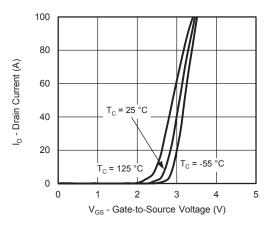
Output Characteristics



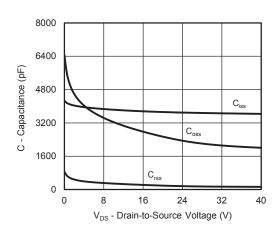
On-Resistance vs. Drain Current



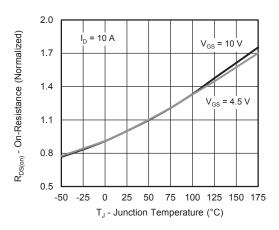
Gate Charge



Transfer Characteristics

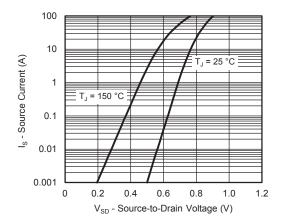


Capacitance

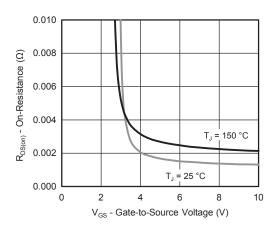


On-Resistance vs. Junction Temperature

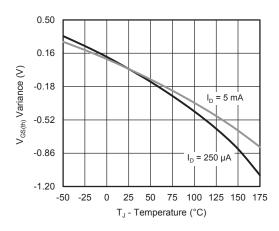




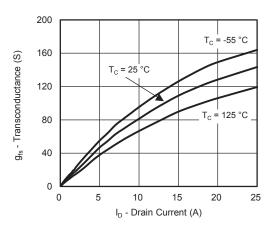
Source Drain Diode Forward Voltage



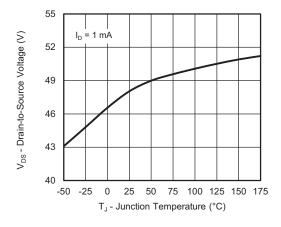
On-Resistance vs. Gate-to Source Voltage



Threshold Voltage



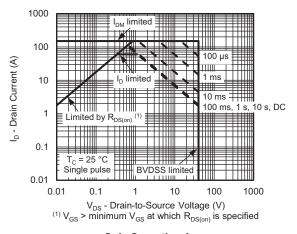
Transconductance



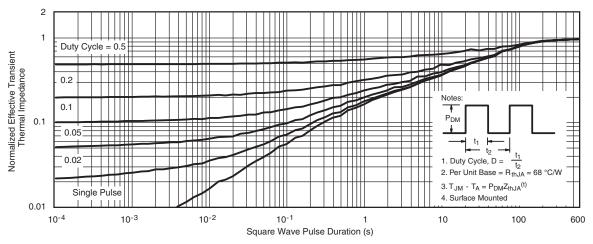
Drain Source Breakdown vs. Junction Temperature

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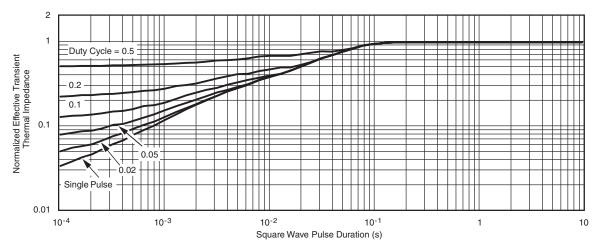


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient





Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75858.

Vishay Siliconix

PowerPAK® SO-8L

Ordering codes for the SQ rugged series power MOSFETs in the PowerPAK SO-8L package:

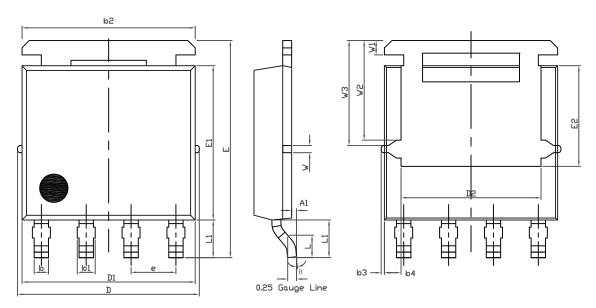
DATASHEET PART NUMBER	OLD ORDERING CODE ^a	NEW ORDERING CODE		
SQJ200EP	-	SQJ200EP-T1_GE3		
SQJ202EP	-	SQJ202EP-T1_GE3		
SQJ401EP	SQJ401EP-T1-GE3	SQJ401EP-T1_GE3		
SQJ402EP	SQJ402EP-T1-GE3	SQJ402EP-T1_GE3		
SQJ403EEP	SQJ403EEP-T1-GE3	SQJ403EEP-T1_GE3		
SQJ403EP	-	SQJ403EP-T1_GE3		
SQJ410EP	SQJ410EP-T1-GE3	SQJ410EP-T1_GE3		
SQJ412EP	SQJ412EP-T1-GE3	SQJ412EP-T1_GE3		
SQJ416EP	-	SQJ416EP-T1_GE3		
SQJ418EP	-	SQJ418EP-T1_GE3		
SQJ422EP	SQJ422EP-T1-GE3	SQJ422EP-T1 GE3		
SQJ423EP	-	SQJ423EP-T1_GE3		
SQJ431EP	SQJ431EP-T1-GE3	SQJ431EP-T1_GE3		
SQJ443EP	SQJ443EP-T1-GE3	SQJ443EP-T1_GE3		
SQJ444EP	-	SQJ444EP-T1_GE3		
SQJ446EP	-	SQJ446EP-T1 GE3		
SQJ456EP	SQJ456EP-T1-GE3	SQJ456EP-T1 GE3		
SQJ457EP	-	SQJ457EP-T1_GE3		
SQJ459EP		SQJ459EP-T1_GE3		
SQJ460AEP		SQJ460AEP-T1 GE3		
	SQJ461EP-T1-GE3	SQJ461EP-T1 GE3		
SQJ461EP	SQJ463EP-T1-GE3			
SQJ463EP		SQJ463EP-T1_GE3		
SQJ465EP	SQJ465EP-T1-GE3	SQJ465EP-T1_GE3		
SQJ469EP	SQJ469EP-T1-GE3	SQJ469EP-T1_GE3		
SQJ474EP	<u>-</u>	SQJ474EP-T1_GE3		
SQJ476EP	-	SQJ476EP-T1_GE3		
SQJ479EP	-	SQJ479EP-T1_GE3		
SQJ486EP	SQJ486EP-T1-GE3	SQJ486EP-T1_GE3		
SQJ488EP	SQJ488EP-T1-GE3	SQJ488EP-T1_GE3		
SQJ500AEP	SQJ500AEP-T1-GE3	SQJ500AEP-T1_GE3		
SQJ840EP	SQJ840EP-T1-GE3	SQJ840EP-T1_GE3		
SQJ844AEP	SQJ844AEP-T1-GE3	SQJ844AEP-T1_GE3		
SQJ850EP	SQJ850EP-T1-GE3	SQJ850EP-T1_GE3		
SQJ858AEP	SQJ858AEP-T1-GE3	SQJ858AEP-T1_GE3		
SQJ868EP	-	SQJ868EP-T1_GE3		
SQJ886EP	SQJ886EP-T1-GE3	SQJ886EP-T1_GE3		
SQJ910AEP	SQJ910AEP-T1-GE3	SQJ910AEP-T1_GE3		
SQJ912AEP	SQJ912AEP-T1-GE3	SQJ912AEP-T1_GE3		
SQJ940EP	SQJ940EP-T1-GE3	SQJ940EP-T1_GE3		
SQJ942EP	SQJ942EP-T1-GE3	SQJ942EP-T1_GE3		
SQJ951EP	SQJ951EP-T1-GE3	SQJ951EP-T1_GE3		
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SQJ956EP	SQJ956EP-T1-GE3	SQJ956EP-T1_GE3		
SQJ960EP	SQJ960EP-T1-GE3	SQJ960EP-T1_GE3		
SQJ963EP	SQJ963EP-T1-GE3	SQJ963EP-T1_GE3		
SQJ968EP	SQJ968EP-T1-GE3	SQJ968EP-T1_GE3		
SQJ980AEP	SQJ980AEP-T1-GE3	SQJ980AEP-T1_GE3		
SQJ992EP	SQJ992EP-T1-GE3	SQJ992EP-T1_GE3		

Note

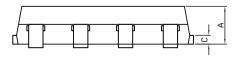
a. Old ordering code is obsolete and no longer valid for new orders

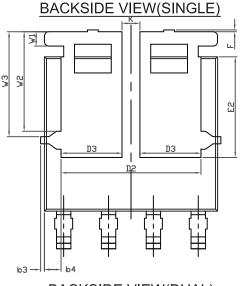
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PowerPAK® SO-8L Case Outline for all Parts



TOPSIDE VIEW





BACKSIDE VIEW(DUAL)



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DIM	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W		0.23			0.009		
W1	0.41			0.016			
W2	2.82			0.111			
W3		2.96			0.117		
q	0°	-	10°	0°	-	10°	

ECN: C15-1203-Rev. A, 07-Sep-15

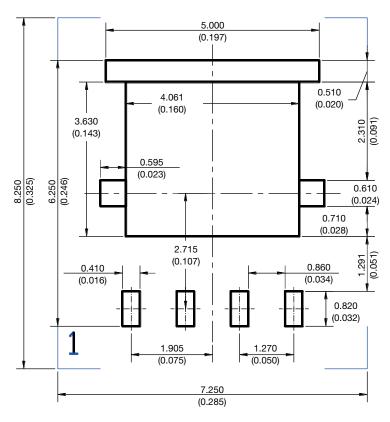
DWG: 6044

Note

· Millimeters will gover



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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Revision: 13-Jun-16 1 Document Number: 91000

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TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C

IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384

NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956

NTE2911 US6M2GTR TK10A80W,S4X(S SSM6P69NU,LF